

MOS INTEGRATED CIRCUIT $\mu PD434004AL$

4M-BIT CMOS FAST SRAM 1M-WORD BY 4-BIT

Description

The μ PD434004AL is a high speed, low power, 4,194,304 bits (1,048,576 words by 4 bits) CMOS static RAM.

Operating supply voltage is 3.3 V \pm 0.3 V.

The $\mu\text{PD434004AL}$ is packaged in a 32-pin plastic SOJ.

Features

• 1,048,576 words by 4 bits organization

• Fast access time: 15, 17, 20 ns (MAX.)

• Output Enable input for easy application

• Single +3.3 V power supply

Ordering Information

Part number	Package	Access time	Supply currer	nt mA (MAX.)
		ns (MAX.)	At operating	At standby
μPD434004ALLE-A15	32-pin plastic SOJ	15	130	5
μPD434004ALLE-A17	(10.16 mm (400))	17	120	
μPD434004ALLE-A20		20	110	

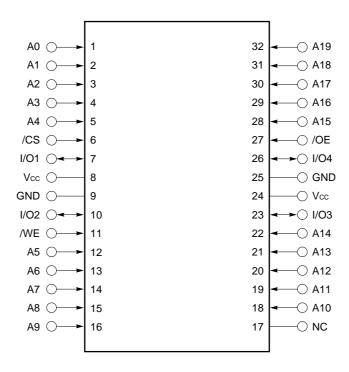
The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

★ Pin Configuration (Marking Side)

/xxx indicates active low signal.

32-pin plastic SOJ (10.16 mm (400)) [μ PD434004ALLE]



A0 - A19 : Address Inputs

I/O1 - I/O4 : Data Inputs / Outputs

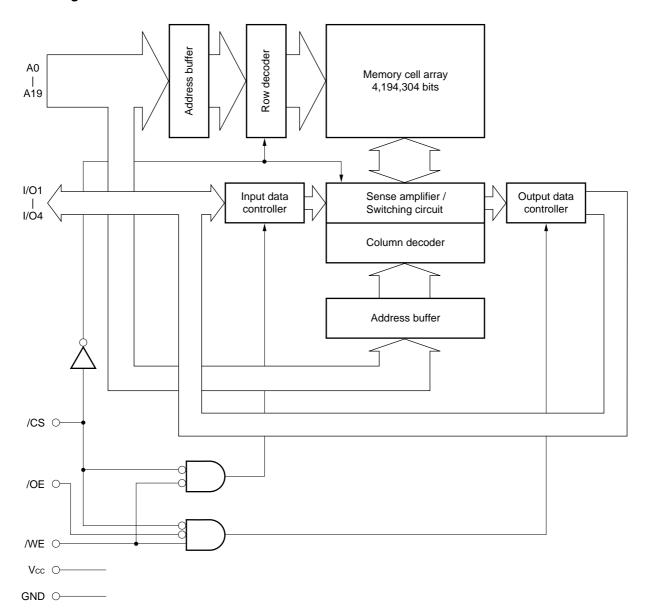
/CS : Chip Select
/WE : Write Enable
/OE : Output Enable
Vcc : Power supply
GND : Ground

NC : No connection

Remark Refer to Package Drawing for the 1-pin index mark.



Block Diagram



Truth Table

/CS	/OE	/WE	Mode	I/O	Supply current
Н	×	×	Not selected	High impedance	Isb
L	L	Н	Read	D оит	Icc
L	×	L	Write	Din	
L	Н	Н	Output disable	High impedance	

Remark ×: Don't care



Electrical Specifications

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	Vcc		-0.5 ^{Note} to +4.6	V
Input / Output voltage	VT		-0.5 ^{Note} to +4.6	V
Operating ambient temperature	TA		0 to 70	°C
Storage temperature	Tstg		-55 to +125	°C

Note -2.0 V (MIN.) (pulse width: 2 ns)

Caution Exposing the device to stress above those listed in Absolute Maximum Rating could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	Vcc		3.0	3.3	3.6	V
High level input voltage	VIH		2.2		Vcc+0.3	٧
Low level input voltage	VIL		-0.3 Note		+0.8	٧
Operating ambient temperature	TA		0		70	°C

Note -2.0 V (MIN.) (pulse width: 2 ns)



DC Characteristics (Recommended Operating Conditions Unless Otherwise Noted)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit	
Input leakage current	lu	VIN = 0 V to Vcc		-2		+2	μΑ
Output leakage current	ILO	$V_{I/O} = 0 V \text{ to } V_{CC},$		-2		+2	μΑ
		/CS = VIH or /OE = VIH	or /WE = VIL				
Operating supply current	Icc	/CS = VIL,	Cycle time : 15 ns			130	mA
		I ₁ /0 = 0 mA,	Cycle time : 17 ns			120	
		Minimum cycle time	Cycle time : 20 ns			110	
Standby supply current	Isa	/CS = VIH, VIN = VIH or	VIL			50	mA
	I _{SB1}	/CS ≥ Vcc - 0.2 V,				5	
		$V_{\text{IN}} \leq 0.2 \text{ V or } V_{\text{IN}} \geq V_{\text{CC}} - 0.2 \text{ V}$					
High level output voltage	Vон	Iон = -4.0 mA	2.4			V	
Low level output voltage	Vol	IoL = +8.0 mA				0.4	V

Remark VIN: Input voltage

Vi/o: Input / Output voltage

Capacitance (T_A = 25 °C, f = 1 MHz)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	Cin	VIN = 0 V			6	pF
Input / Output capacitance	C _{I/O}	V ₁ /O = 0 V			10	pF

Remarks 1. VIN: Input voltage

Vi/o: Input / Output voltage

2. These parameters are periodically sampled and not 100% tested.

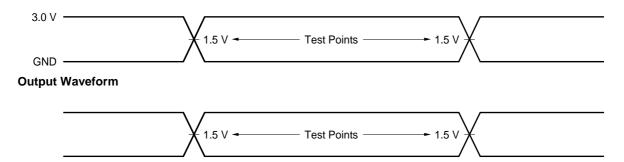
Data Sheet M12225EJ5V0DS00 5



AC Characteristics (Recommended Operating Conditions Unless Otherwise Noted)

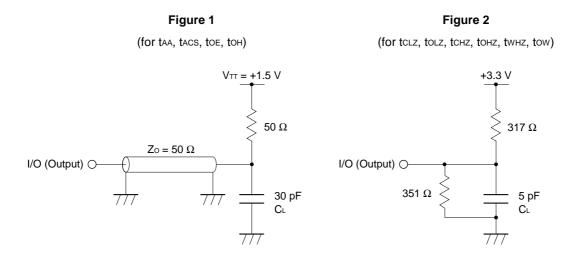
AC Test Conditions

Input Waveform (Rise and Fall Time ≤ 3 ns)



Output Load

AC characteristics directed with the note should be measured with the output load shown in **Figure 1** or **Figure 2**.



Remark C_L includes capacitances of the probe and jig, and stray capacitances.



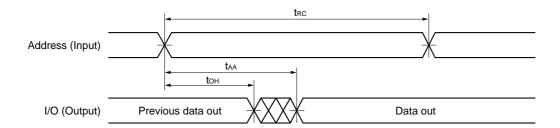
Read Cycle

Parameter	Symbol	μPD434004AL-A15		μPD4340	34004AL-A17 μPD4340		04AL-A20	Unit	Notes
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Read cycle time	trc	15		17		20		ns	
Address access time	taa		15		17		20	ns	1
/CS access time	tacs		15		17		20	ns	
/OE access time	toe		7		8		10	ns	
Output hold from address change	tон	3		3		3		ns	
/CS to output in low impedance	tclz	3		3		3		ns	2, 3
/OE to output in low impedance	tolz	0		0		0		ns	
/CS to output in high impedance	tснz		7		8		8	ns	
/OE to output hold in high impedance	tонz		7		8		8	ns	

Notes 1. See the output load shown in Figure 1.

- 2. Transition is measured at \pm 200 mV from steady-state voltage with the output load shown in **Figure 2**.
- 3. These parameters are periodically sampled and not 100% tested.

Read Cycle Timing Chart 1 (Address Access)

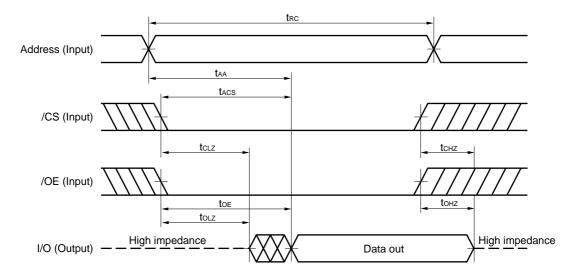


Remarks 1. In read cycle, /WE should be fixed to high level.

2. /CS = /OE = VIL



Read Cycle Timing Chart 2 (/CS Access)



Caution Address valid prior to or coincident with /CS low level input.

Remark In read cycle, /WE should be fixed to high level.



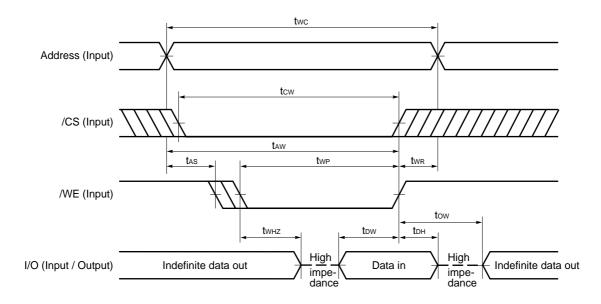
Write Cycle

Parameter	Symbol	μPD4340	04AL-A15	μPD4340	04AL-A17	μPD4340	04AL-A20	Unit	Notes
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Write cycle time	twc	15		17		20		ns	
/CS to end of write	tcw	10		11		12		ns	
Address valid to end of write	taw	10		11		12		ns	
Write pulse width	twp	10		11		12		ns	
Data valid to end of write	tow	7		8		9		ns	
Data hold time	tон	0		0		0		ns	
Address setup time	tas	0		0		0		ns	
Write recovery time	twr	1		1		1		ns	
/WE to output in high impedance	twnz		7		8		8	ns	1, 2
Output active from end of write	tow	3		3		3		ns	

Notes 1. Transition is measured at \pm 200 mV from steady-state voltage with the output load shown in **Figure 2**.

2. These parameters are periodically sampled and not 100% tested.

Write Cycle Timing Chart 1 (/WE Controlled)



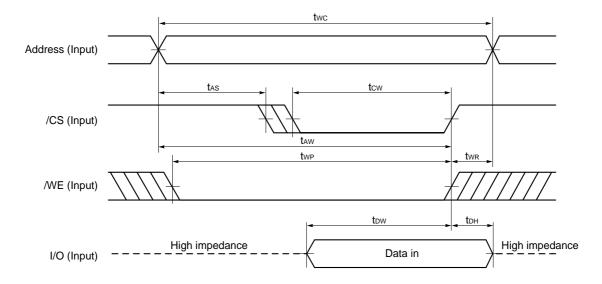
Caution /CS or /WE should be fixed to high level during address transition.

Remarks 1. Write operation is done during the overlap time of a low level /CS and a low level /WE.

- 2. During twHZ, I/O pins are in the output state, therefore the input signals must not be applied to the output.
- 3. When /WE is at low level, the I/O pins are always high impedance. When /WE is at high level, read operation is executed. Therefore /OE should be at high level to make the I/O pins high impedance.



Write Cycle Timing Chart 2 (/CS Controlled)



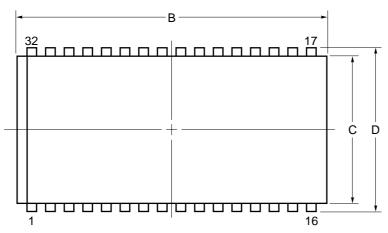
Caution /CS or /WE should be fixed to high level during address transition.

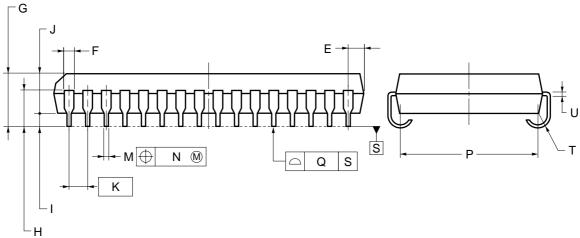
Remark Write operation is done during the overlap time of a low level /CS and a low level /WE.



Package Drawing

32-PIN PLASTIC SOJ (10.16mm (400))





NOTE

Each lead centerline is located within 0.12 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
В	21.26±0.2
С	10.16
D	11.18±0.2
Е	1.005±0.1
F	0.74
G	3.5±0.2
Н	2.545±0.2
I	0.8 MIN.
J	2.6
K	1.27(T.P.)
М	0.40±0.10
N	0.12
Р	9.4±0.20
Q	0.1
Т	R0.85
U	$0.20^{+0.10}_{-0.05}$

P32LE-400A-1



Recommended Soldering Conditions

Please consult with our sales offices for soldering conditions of the μ PD434004AL.

Type of Surface Mount Device

 μ PD434004ALLE : 32-pin plastic SOJ (10.16 mm (400))

NEC μ PD434004AL

[MEMO]

NEC μ PD434004AL

[MEMO]



- NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

- The information in this document is current as of May, 2000. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of
 third parties by or arising from the use of NEC semiconductor products listed in this document or any other
 liability arising from the use of such products. No license, express, implied or otherwise, is granted under any
 patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of customer's equipment shall be done under the full responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
 agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
 risks of damage to property or injury (including death) to persons arising from defects in NEC
 semiconductor products, customers must incorporate sufficient safety measures in their design, such as
 redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
 - "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.
 - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

M8E 00.4